## 9 Static fields in dielectric media

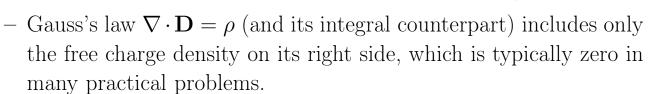
Copyright ©2021 Reserved — no parts of this set of lecture notes (Lects. 1-39) may be reproduced without permission from the author.

- Summarizing important results from last lecture:
  - within a dielectric medium, displacement

$$\mathbf{D} = \epsilon \mathbf{E} = \epsilon_o \mathbf{E} + \mathbf{P},$$

and if the permittivity  $\epsilon = \epsilon_r \epsilon_o$  is known, **D** and **E** can be calculated from free surface charge  $\rho_s$  or volume charge  $\rho$  in the region without resorting to **P**.

– on surfaces separating perfect dielectrics,  $\hat{n} \cdot (\mathbf{D}^+ - \mathbf{D}^-) = 0$  typically, while  $\hat{n} \cdot \mathbf{D}^+ = \rho_s$  on a conductor-dielectric interface (with  $\hat{n}$  pointing from the conductor toward the dielectric).

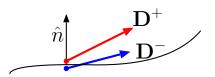


- once  $\mathbf{D}$  and  $\mathbf{E}$  have been calculated (typically using the boundary condition equations), polarization  $\mathbf{P}$  can be obtained as

$$\mathbf{P} = \mathbf{D} - \epsilon_o \mathbf{E}$$

if needed.

These rules will be used in the examples in this section.



**Example 1:** A perfect dielectric slab having a finite thickness W in the x direction is surrounded by free space and has a constant electric field  $\mathbf{E} = 18\hat{x} \text{ V/m}$  in its exterior. Induced polarization of bound charges inside dielectric reduces the electric field strength inside the slab from  $18\hat{x} \text{ V/m}$  to  $\mathbf{E} = 3\hat{x} \text{ V/m}$ . What are the displacement field  $\mathbf{D}$  and polarization  $\mathbf{P}$  outside and inside the slab, and what are the dielectric constant  $\epsilon_r$  and electric susceptibility  $\chi_e$  of the slab?

**Solution:** Displacement field outside the slab, where  $\epsilon = \epsilon_o$ , must be

$$\mathbf{D} = \epsilon_o \mathbf{E} = \hat{x} 18 \epsilon_o \frac{\mathbf{C}}{\mathbf{m}^2}.$$

The outside polarization  $\mathbf{P}$  is of course zero. Boundary conditions at the interface of the slab with free space require the continuity of normal component of  $\mathbf{D}$  and tangential component of  $\mathbf{E}$  — both of these conditions would be satisfied if we were to take  $\mathbf{D} = \hat{x}18\epsilon_o$  C/m<sup>2</sup> also within the dielectric slab. Thus, with  $\mathbf{E} = 3\hat{x}$  V/m inside the slab, the condition  $\mathbf{D} = \epsilon_{slab}\mathbf{E}$  within the slab requires that

$$\epsilon_{slab} = 6\epsilon_o$$
.

Consequently, the dielectric constant of the slab is

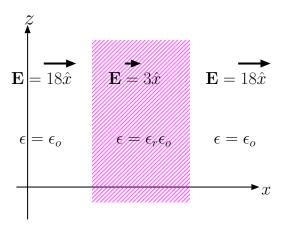
$$\epsilon_r = 1 + \chi_e = \frac{\epsilon_{slab}}{\epsilon_o} = 6$$

and its electric susceptibility is

$$\chi_e = \epsilon_r - 1 = 5.$$

Finally, since  $\mathbf{D} = \epsilon_o \mathbf{E} + \mathbf{P}$  in general, polarization  $\mathbf{P}$  inside the slab is

$$\mathbf{P} = \mathbf{D} - \epsilon_o \mathbf{E} = \hat{x} 18\epsilon_o - \epsilon_o 3\hat{x} = \hat{x} 15\epsilon_o \frac{\mathbf{C}}{\mathbf{m}^2}.$$



• Our revised definition of displacement  $\mathbf{D} = \epsilon \mathbf{E}$ , where  $\epsilon = \epsilon_r \epsilon_o$ , implies, when combined with  $\mathbf{E} = -\nabla V$  and  $\nabla \cdot \mathbf{D} = \rho$ , a revised form of Poisson's equation

$$\nabla^2 V = -\frac{\rho}{\epsilon},$$

- provided that dielectric constant  $\epsilon_r$  is independent of position so that  $\nabla \cdot \mathbf{D} = \nabla \cdot (\epsilon \mathbf{E}) = \epsilon \nabla \cdot \mathbf{E}$  is a valid intermediate step in the derivation of Poisson's equation.
- Under the same condition Laplace's equation  $\nabla^2 V = 0$  also remains valid.
- Dielectrics where  $\epsilon_r$  is independent of position are said to be homogeneous.
  - $\circ$  In **inhomogeneous** dielectrics where  $\epsilon$  varies with position neither equation is valid, and one has to resort to the full form of Gauss's law in field and potential calculations.

## In other words, don't use Laplace's/Poisson's equations in inhomogeneous media.

In the next example we have two homogeneous slabs side-by-side making up an inhomogeneous configuration. In that case we can use Laplace/Poisson within the slabs one at a time and then match the results at the boundary using boundary condition equations as shown.

**Example 2:** A pair of infinite conducting plates at z = 0 and z = 2 m carry equal and opposite surface charge densities of  $-2\epsilon_o$  C/m<sup>2</sup> and  $2\epsilon_o$  C/m<sup>2</sup>, respectively. Determine V(2) if V(0) = 0 and regions 0 < z < 1 m and 1 < z < 2 m are occupied by perfect dielectrics with permittivities of  $\epsilon_o$  and  $2\epsilon_o$ , respectively.

**Solution:** Given that V(0) = 0, we assume V(z) = Az, for some constant A in the homogeneous region 0 < z < 1 m, since V(z) = Az satisfies the Laplace's equation as well as the boundary condition at z = 0.

This gives V(1) = A at z = 1 m, which then implies that we can take V(z) = A + B(z-1) for the second homogeneous region 1 < z < 2 m having a different permittivity than the region below.

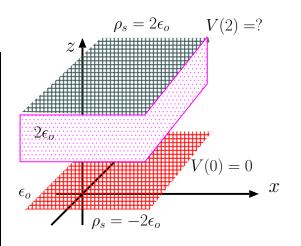
To determine the constants A and B, we will make use of boundary conditions at z=0 and z=1 m interfaces:

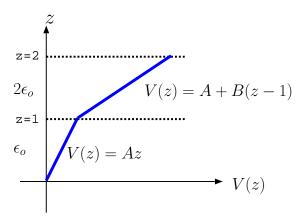
• In the region 0 < z < 1 m, the electric field  $\mathbf{E} = -\nabla(Az) = -A\hat{z}$ , and, therefore displacement  $\mathbf{D} = \epsilon_1 \mathbf{E} = -\epsilon_o A\hat{z}$ . Hence, the pertinent boundary condition  $\hat{z} \cdot \mathbf{D}(0) = \rho_s$  yields

$$\hat{z} \cdot \mathbf{D}(0) = -\epsilon_o A = -2\epsilon_o \implies A = 2\epsilon_o$$

• Just below z = 1 m the displacement is  $\mathbf{D}(1^-) = -\epsilon_o A \hat{z} = -2\epsilon_o \hat{z}$  as we found out above. Above z = 1 m, the electric field is  $\mathbf{E} = -\nabla(A + B(z - 1)) = -B\hat{z}$ , and, therefore,  $\mathbf{D}(1^+) = -2\epsilon_o B \hat{z}$  just above z = 1 m. Hence, the pertinent boundary condition  $\hat{z} \cdot (\mathbf{D}(1^+) - \mathbf{D}(1^-)) = 0$  yields

$$\hat{z} \cdot (-2\epsilon_o B\hat{z} - (-2\epsilon_o \hat{z})) = -2\epsilon_o B + 2\epsilon_o = 0 \implies B = 1.$$





Based on above calculations of constants A and B, the potential solution for the region is

$$V(z) = \begin{cases} 2z \, V, & 0 < z < 1 \\ 2 + (z - 1) \, V, & 1 < z < 2. \end{cases}$$

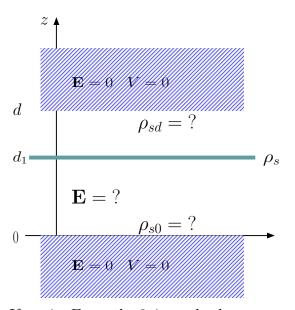
It follows that V(2) = 3 V.

Note that electric fields  $-2\hat{z}$  V/m and  $-\hat{z}$  V/m in the bottom and top layers point from high to low potential regions. Electric field **E** is discontinuous at the boundary at z=1 m while displacement **D** is continuous — the continuity of normally directed **D** is demanded by boundary condition equations in the absence of surface charge.

**Example 3:** A pair of infinite conducting plates at z = 0 and z = d are grounded and have equal potentials, say, V = 0. The region 0 < z < d is occupied by free space (i.e.,  $\epsilon = \epsilon_o$ ) except that an infinite charge sheet with a static surface charge density  $\rho_s$  is located at  $z = d_1 < d$ . Determine (a) the electrostatic field  $\mathbf{E}(z)$  in regions  $0 < z < d_1$  and  $d_1 < z < d$ , and (b) the surface charge densities  $\rho_{s0}$  and  $\rho_{sd}$  at z = 0 and z = d on conductor surfaces if  $d_1 = d/2$ .

**Solution:** (a) Laplace's equation for the given geometry requires a linear (in z) potential solution in regions  $0 < z < d_1$  and  $d_1 < z < d$ . Since electrostatic  $\mathbf{E} = -\nabla V$ , we can therefore represent the electric field in these regions as

$$\mathbf{E} = \begin{cases} -\hat{z}V_o/d_1, & 0 < z < d_1 \\ +\hat{z}V_o/d_2, & d_1 < z < d \end{cases}$$



If  $\rho_s$  in Example 3 is a slowly-varying function of time, then slowly varying  $\mathbf{E}$ ,  $\rho_{s0}$ , and  $\rho_{sd}$  calculated with instantaneous values of  $\rho_s$  would constitute quasi-static solutions which are valid so long as  $d \ll c/f$ , with f the highest frequency in  $\rho_s(t)$ .

where  $V_o \equiv V(d_1)$  and  $d_2 \equiv d - d_1$ . Hence,

$$\mathbf{D} = \epsilon_o \mathbf{E} = \begin{cases} -\hat{z} \epsilon_o V_o / d_1, & 0 < z < d_1 \\ +\hat{z} \epsilon_o V_o / d_2, & d_1 < z < d \end{cases},$$

and Maxwell's boundary condition equation applied on  $z = d_1$  surface is

$$\hat{z} \cdot (\mathbf{D}(d_1^+) - \mathbf{D}(d_1^-)) = \rho_s \implies \epsilon_o V_o \left(\frac{1}{d_2} + \frac{1}{d_1}\right) = \rho_s.$$

Thus

$$V_o = \frac{\rho_s}{\epsilon_o} \left( \frac{1}{d_2} + \frac{1}{d_1} \right)^{-1} = \frac{\rho_s}{\epsilon_o} \frac{d_1 d_2}{d_1 + d_2} = \frac{\rho_s}{\epsilon_o} \frac{d_1 d_2}{d}.$$

Substituting  $V_o$  back into the expression for **E**, we have

$$\mathbf{E} = \begin{cases} -\hat{z} \frac{\rho_s}{\epsilon_o} \frac{d_2}{d}, & 0 < z < d_1 \\ +\hat{z} \frac{\rho_s}{\epsilon_o} \frac{d_1}{d}, & d_1 < z < d. \end{cases}$$

(b) The surface charge at z=0 can be found by evaluating  $\hat{z} \cdot \mathbf{D} = \hat{z} \cdot \epsilon_o \mathbf{E}$  at z=0. Hence,

$$\rho_{s0} = \hat{z} \cdot \epsilon_o \mathbf{E}(0) = -\frac{d_2}{d} \rho_s \ \overrightarrow{d_1 = d/2} \ -\frac{\rho_s}{2}.$$

Likewise,

$$\rho_{sd} = -\hat{z} \cdot \epsilon_o \mathbf{E}(d) = -\frac{d_1}{d} \rho_s \ \overrightarrow{d_1 = d/2} \ -\frac{\rho_s}{2}.$$

**Example 4:** Between a pair of infinite conducting plates at z = 0 and z = 2 m, the medium is a perfect dielectric with an **inhomogeneous** permittivity of

$$\epsilon(z) = \frac{4\epsilon_o}{4-z}.$$

Determine the electric potential V(2) on the top plate if V(0) = 0 and the surface charge density is  $\rho_s = 2\epsilon_o \text{ C/m}^2$  on the bottom plate at z = 0. Note that Laplace's equation cannot be used in this problem since the medium is inhomogeneous.

Solution: Consider Gauss's law

$$\nabla \cdot (\epsilon \mathbf{E}) = \rho$$

with  $\rho = 0$  in the region 0 < z < 2 m. Assuming that  $\mathbf{E} = \hat{z}E_z(z)$ , because the geometry is invariant in x and y, we have

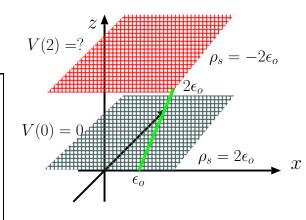
$$\nabla \cdot (\epsilon \mathbf{E}) = 0 \implies \frac{\partial}{\partial z} (\epsilon E_z) = 0 \implies \epsilon E_z = \text{constant.}$$

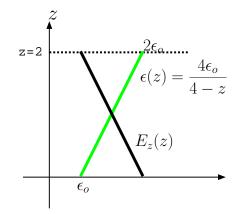
Thus the product  $\epsilon E_z$  is invariant with respect to coordinate z, which implies that

$$\epsilon(z)E_z(z) = \epsilon(0)E_z(0) \implies E_z(z) = \frac{\epsilon(0)}{\epsilon(z)}E_z(0) = E_z(0)(1 - \frac{z}{4})$$

after substituting for  $\epsilon(z)$ . To identify  $E_z(0)$ , we apply the bottom boundary condition  $\hat{z} \cdot \mathbf{D}(0) = \rho_s$ , and obtain

$$D_z(0) = \epsilon(0)E_z(0) = 2\epsilon_o \implies E_z(0) = \frac{2\epsilon_o}{\epsilon(0)} = 2\frac{V}{m}.$$





To determine V(2), we integrate  $\mathbf{E} = \hat{z}2(1-\frac{z}{4})$  V/m from top to bottom plate (grounded), obtaining

$$V(2) = \int_{z=2}^{0} \mathbf{E} \cdot d\mathbf{l} = \int_{z=2}^{0} 2(1 - \frac{z}{4}) dz$$
$$= 2(z - \frac{z^{2}}{8})|_{2}^{0} = -2(2 - \frac{4}{8}) = -2 \cdot \frac{3}{2} = -3 \text{ V}.$$